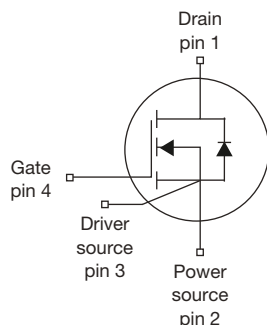
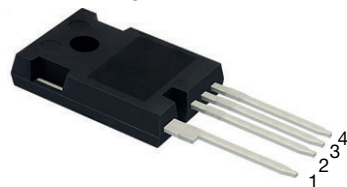


MaxSiC® 1200 V N-Channel SiC MOSFET



RoHS
COMPLIANT
HALOGEN
FREE

TO-247AD 4L

Marking Code: Q120A063SL

PRODUCT SUMMARY

V_{DS} (V) at T_J max.	1200	
$R_{DS(on)}$ typ. (m Ω) at 25 °C	$V_{GS} = 18$ V	63
Q_g typ. (nC)	61	
I_D (A)	39	
C_{oss} typ. (pF)	70	
P_D (W)	205	
Configuration	Single	

ORDERING INFORMATION

Package	TO-247AD 4L
Lead (Pb)-free and halogen-free	MXPQ120A063SL-GE3

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	1200	V
Gate-source voltage	V_{GS}	-10 / +22	
Recommended operation voltage of gate-source	V_{GSOP}	-5 to -3 / +18	
Continuous drain current	I_D	39	A
Pulsed drain current ^a	I_{DM}	78	
Short-circuit withstand time ^b	T_{SC}	3	μ s
Maximum power dissipation	P_D	205	W
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +175	°C
Soldering recommendations (peak temperature)	For 10 s	260	°C
Single pulse avalanche energy ^c	E_{AS}	162	mJ

Notes

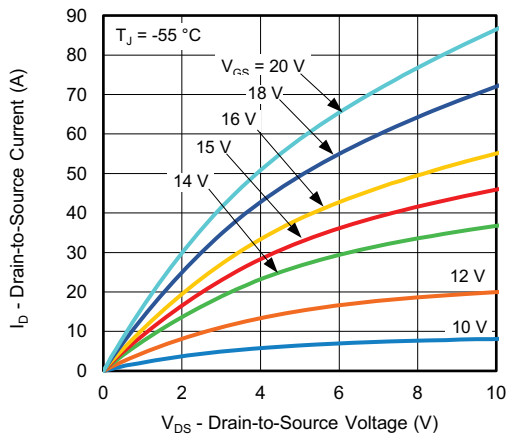
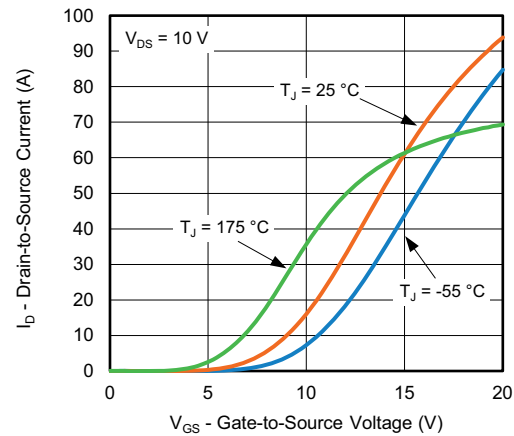
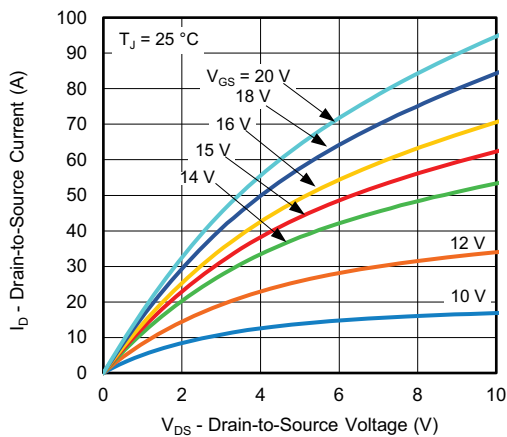
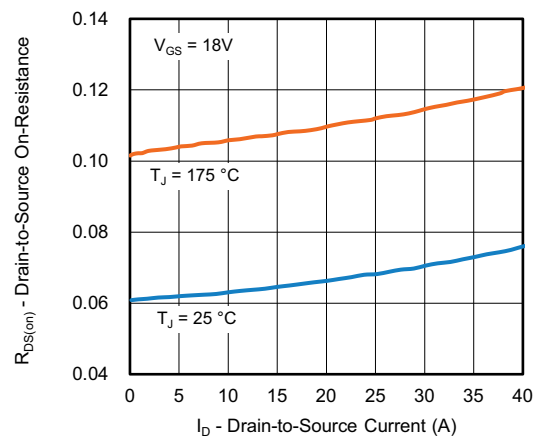
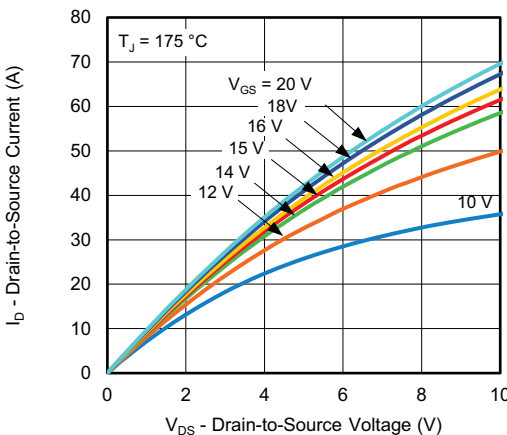
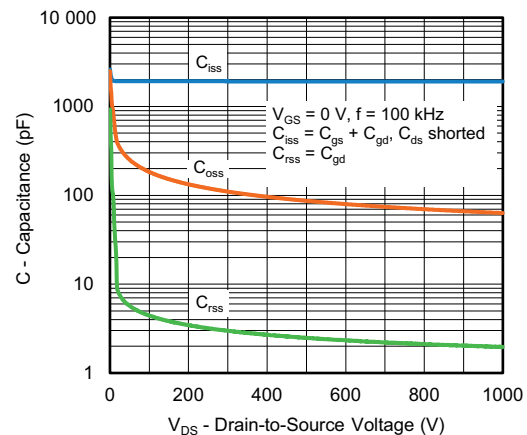
- Repetitive rating; pulse width limited by maximum junction temperature
- $V_{GS} = 18$ V, $V_{DS} = 800$ V, $R_{g(ext)} = 20$ Ω , verified by the design / characterization
- $T_J = 25$ °C, $V_{DD} = 120$ V, $L = 1$ mH, $V_{GS} = 18$ V, $I_{AS} = 18$ A, verified by the design / characterization

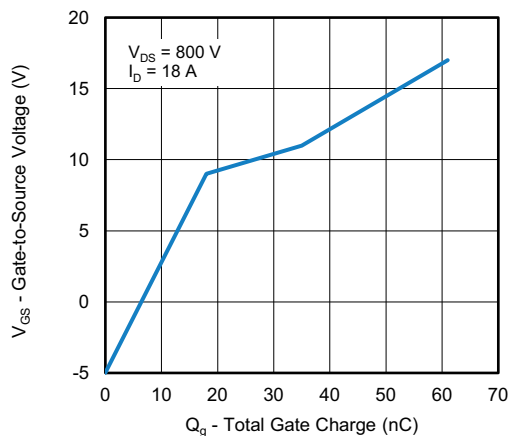
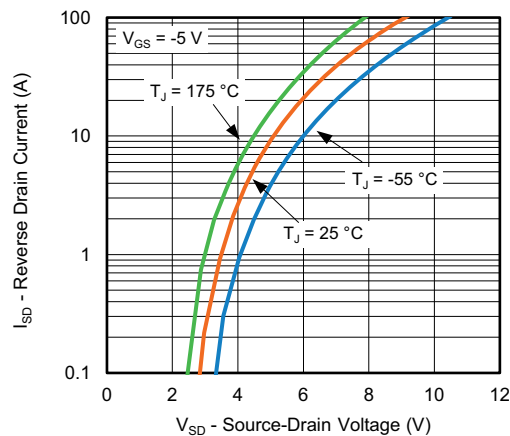
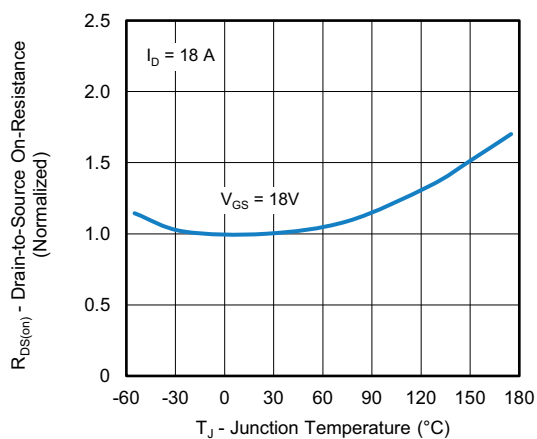
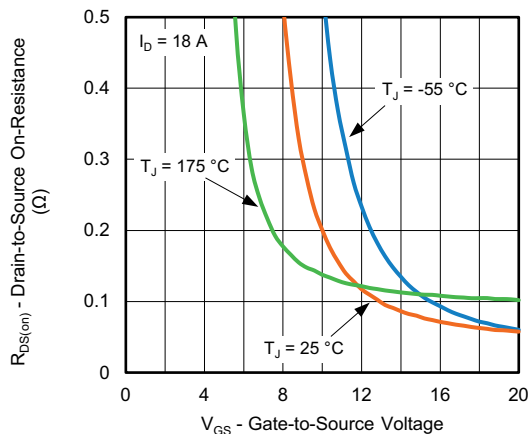
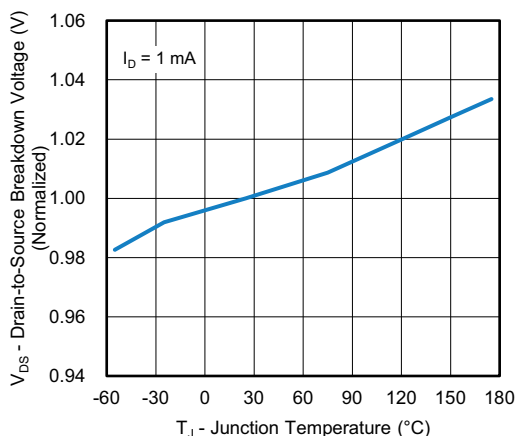
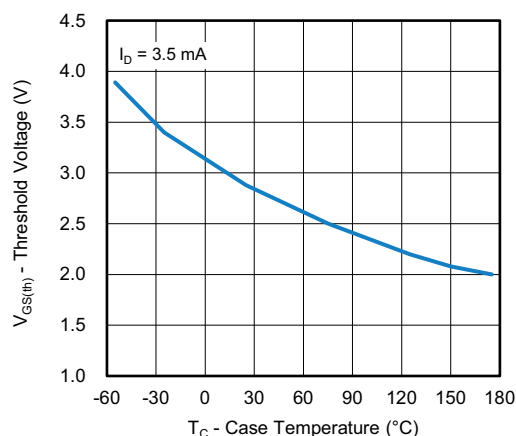
THERMAL RESISTANCE RATINGS

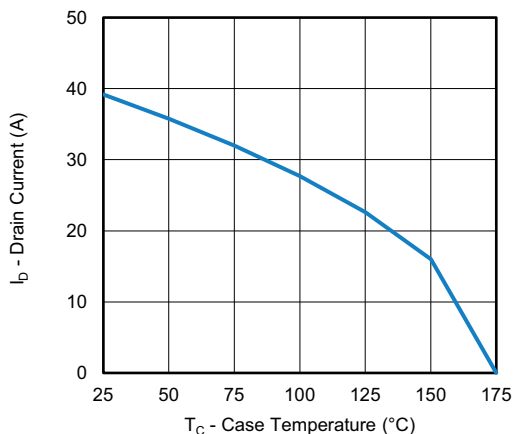
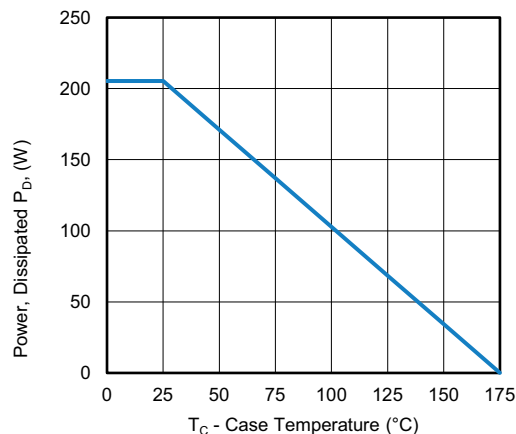
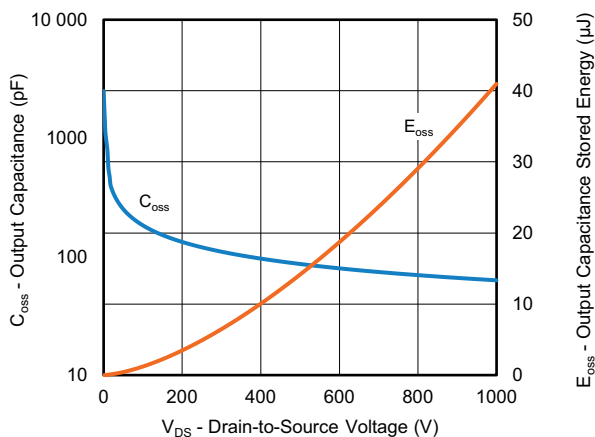
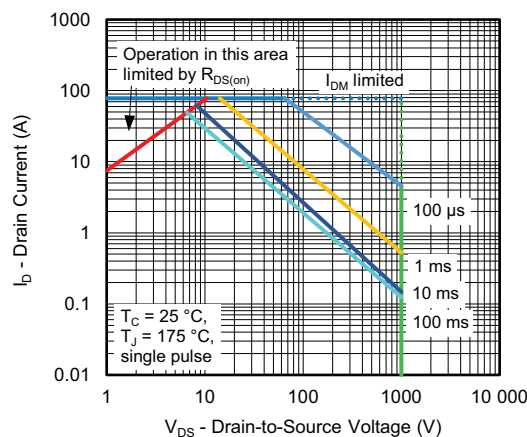
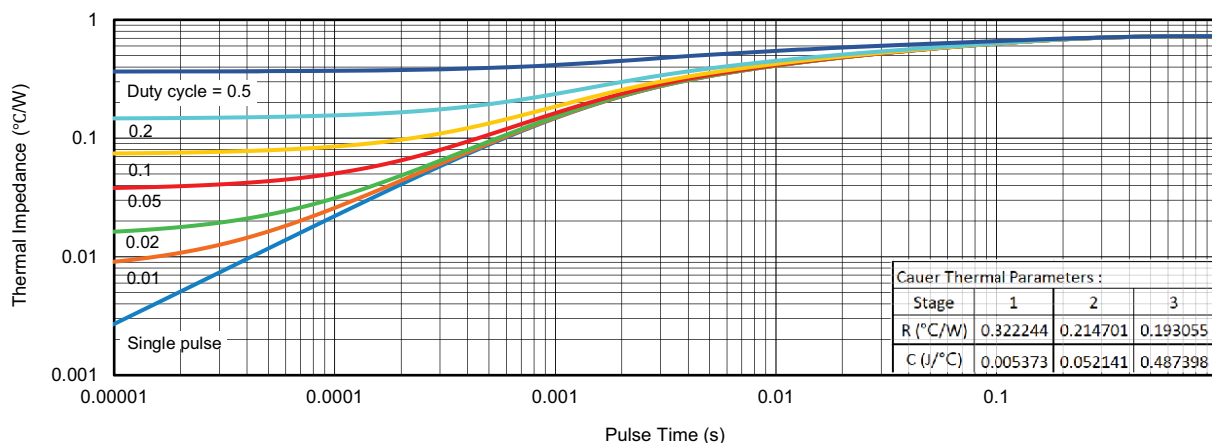
PARAMETER	SYMBOL	TYP.	MAX.	UNIT
Maximum junction-to-ambient	R_{thJA}	-	40	°C/W
Maximum junction-to-case (drain)	R_{thJC}	-	0.73	

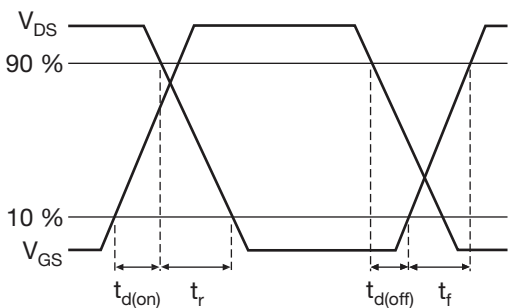
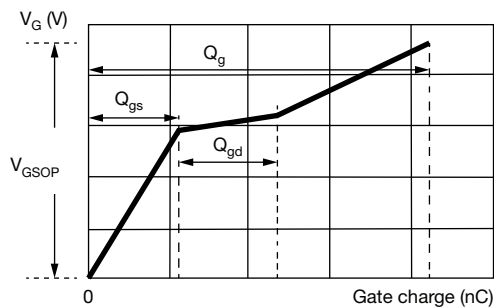
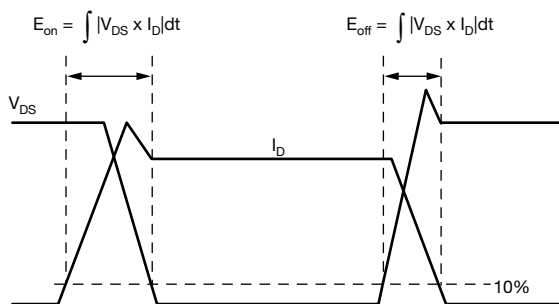
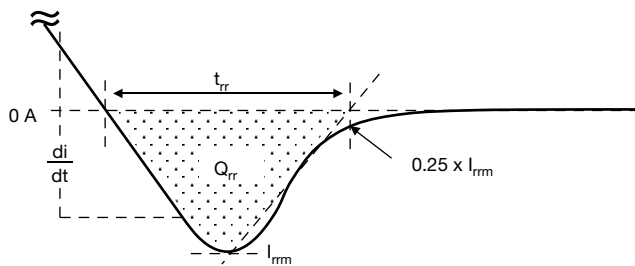
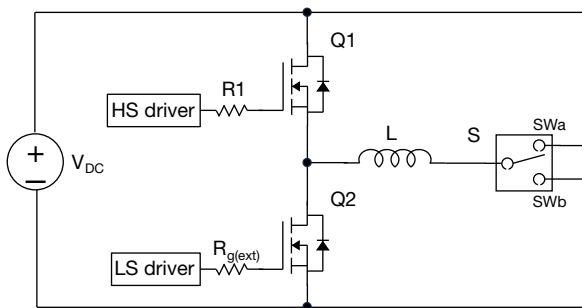
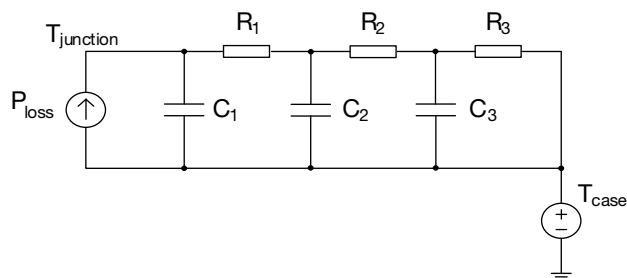


SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = 1 mA		1200	-	-	V
Gate-source threshold voltage (N)	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 3.5 mA		-	2.9	-	V
		V _{DS} = V _{GS} , I _D = 3.5 mA, T _J = 175 °C		-	2.0	-	V
Gate-source leakage	I _{GSS}	V _{GS} = 22 V, V _{DS} = 0 V		-	-	100	nA
		V _{GS} = -10 V, V _{DS} = 0 V		-	-	-100	
Zero gate voltage drain current	I _{DSS}	V _{DS} = 1200 V, V _{GS} = 0 V		-	-	10	μA
Drain-source on-state resistance	R _{DS(on)}	V _{GS} = 15 V, I _D = 18 A		-	75	94	mΩ
		V _{GS} = 18 V, I _D = 18 A		-	63	79	
		V _{GS} = 18 V, I _D = 18 A, T _J = 175 °C		-	107	-	
Transconductance	g _{fs}	V _{DS} = 10 V, I _D = 18 A		-	7	-	S
Dynamic							
Input capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 800 V, f = 100 KHz		-	1909	-	pF
Output capacitance	C _{oss}			-	70	-	
Reverse transfer capacitance	C _{rss}			-	2	-	
Total gate charge	Q _g	V _{GS} = -5 V ~ 18 V, I _D = 18 A, V _{DS} = 800 V		-	61	-	nC
Gate-source charge	Q _{gs}			-	18	-	
Gate-drain charge	Q _{gd}			-	17	-	
Gate Resistance	R _g	V _{DS} = 0 V, f = 1 MHz		-	3	-	Ω
Switching Characteristics							
Turn-on delay time	t _{d(on)}	V _{GS} = -5 V ~ 18 V, I _D = 18 A, V _{DS} = 800 V, R _{g(ext)} = 4.4 Ω	T _J = 25 °C	-	17	-	ns
Rise time	t _r		T _J = 175 °C	-	15	-	
			T _J = 25 °C	-	14	-	
			T _J = 175 °C	-	13	-	
			T _J = 25 °C	-	21	-	
Turn-off delay time	t _{d(off)}		T _J = 175 °C	-	23	-	
			T _J = 25 °C	-	10	-	
			T _J = 175 °C	-	10	-	
Turn-on switching energy	E _{on}		T _J = 25 °C	-	175	-	μJ
			T _J = 175 °C	-	151	-	
Turn-off switching energy	E _{off}		T _J = 25 °C	-	57	-	
			T _J = 175 °C	-	56	-	
Body Diode Ratings and Characteristic							
Forward diode voltage	V _{SD}	V _{GS} = -5 V, I _{SD} = 9 A, T _J = 25 °C		-	4.8	-	V
Continuous diode forward current	I _{SD}	V _{GS} = -5 V, T _J = 25 °C		-	-	29	A
Pulsed diode forward current	I _{SDM}			-	-	78	
Reverse recovery time	t _{rr}	V _{GS} = -5 V, I _{SD} = 18 A, V _R = 800 V, di/dt = 1000 A/μs		-	18	-	ns
Reverse recovery charge	Q _{rr}			-	60	-	nC
Reverse recovery current	I _{RRM}			-	6	-	A

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Fig. 1 - Typical Output Characteristics

Fig. 4 - Typical Transfer Characteristics

Fig. 2 - Typical Output Characteristics

Fig. 5 - Normalized On-Resistance vs. Drain Current

Fig. 3 - Typical Output Characteristics

Fig. 6 - Typical Capacitance vs. Drain-to-Source Voltage


Fig. 7 - Typical Gate Charge vs. Gate-to-Source Voltage

Fig. 10 - Typical Source-Drain Diode Forward Voltage

Fig. 8 - Normalized On-Resistance vs. Temperature

Fig. 11 - On-Resistance vs. Gate-to-Source Voltage

Fig. 9 - Drain-to-Source Voltage vs. Temperature

Fig. 12 - Threshold Voltage vs. Case Temperature

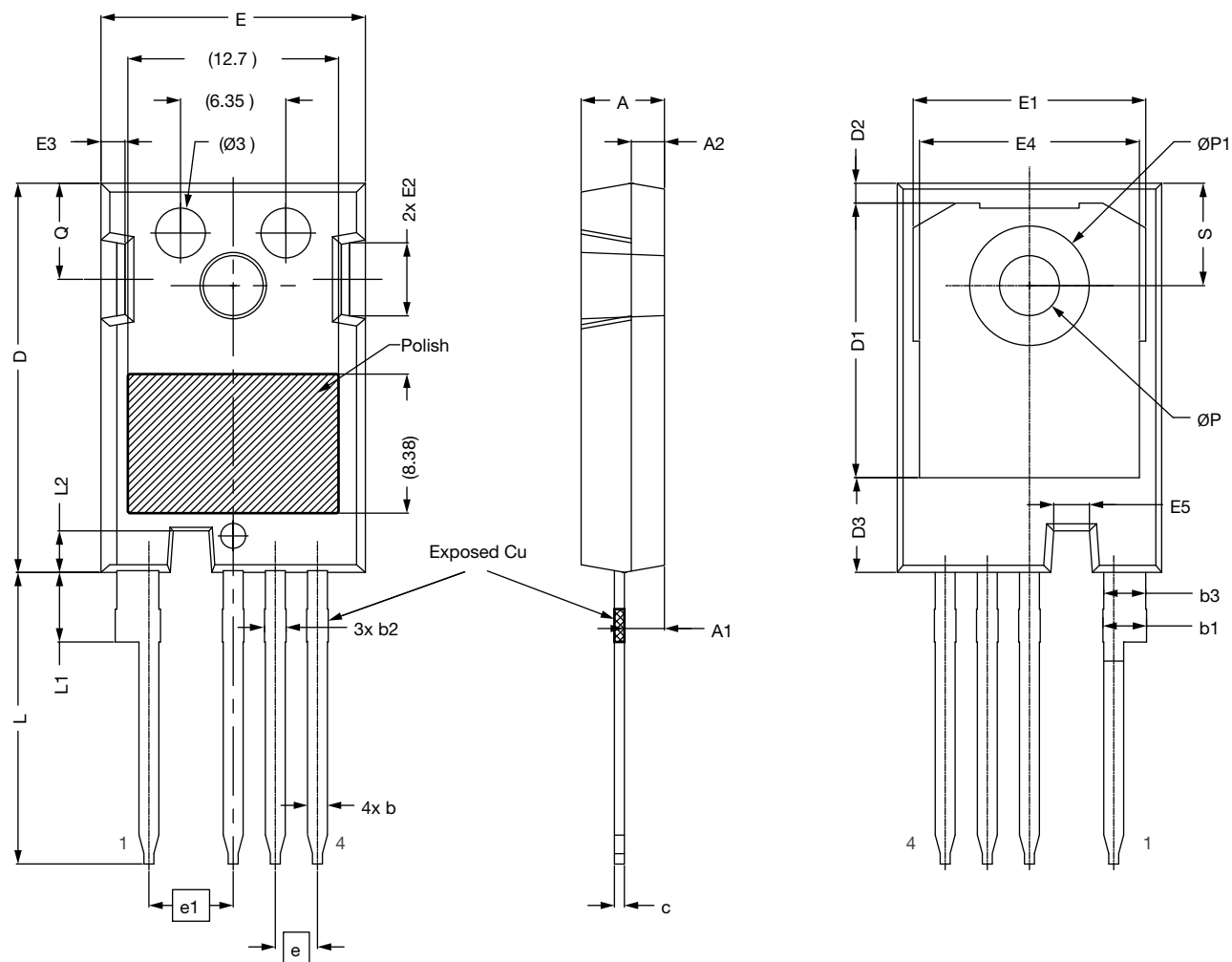

Fig. 13 - Drain Current vs. Case Temperature

Fig. 15 - Power, Dissipated P_D vs. Case Temperature

Fig. 14 - Output Capacitance and its Stored Energy vs. Drain-to-Source Voltage

Fig. 16 - Safe Operating Area

Fig. 17 - Transient Thermal Impedance


Fig. 18 - Waveforms of Switching Time

Fig. 21 - Waveforms for Gate Charge

Fig. 19 - Waveforms for Switching Energy

Fig. 22 - Waveforms for Reverse Recovery

Fig. 20 - Switching and Reverse Diode Characteristics Measurement Circuit

Fig. 23 - Thermal Equivalent Circuit



Case Outline for TO-247AD 4L Package

FACILITY CODE: 9





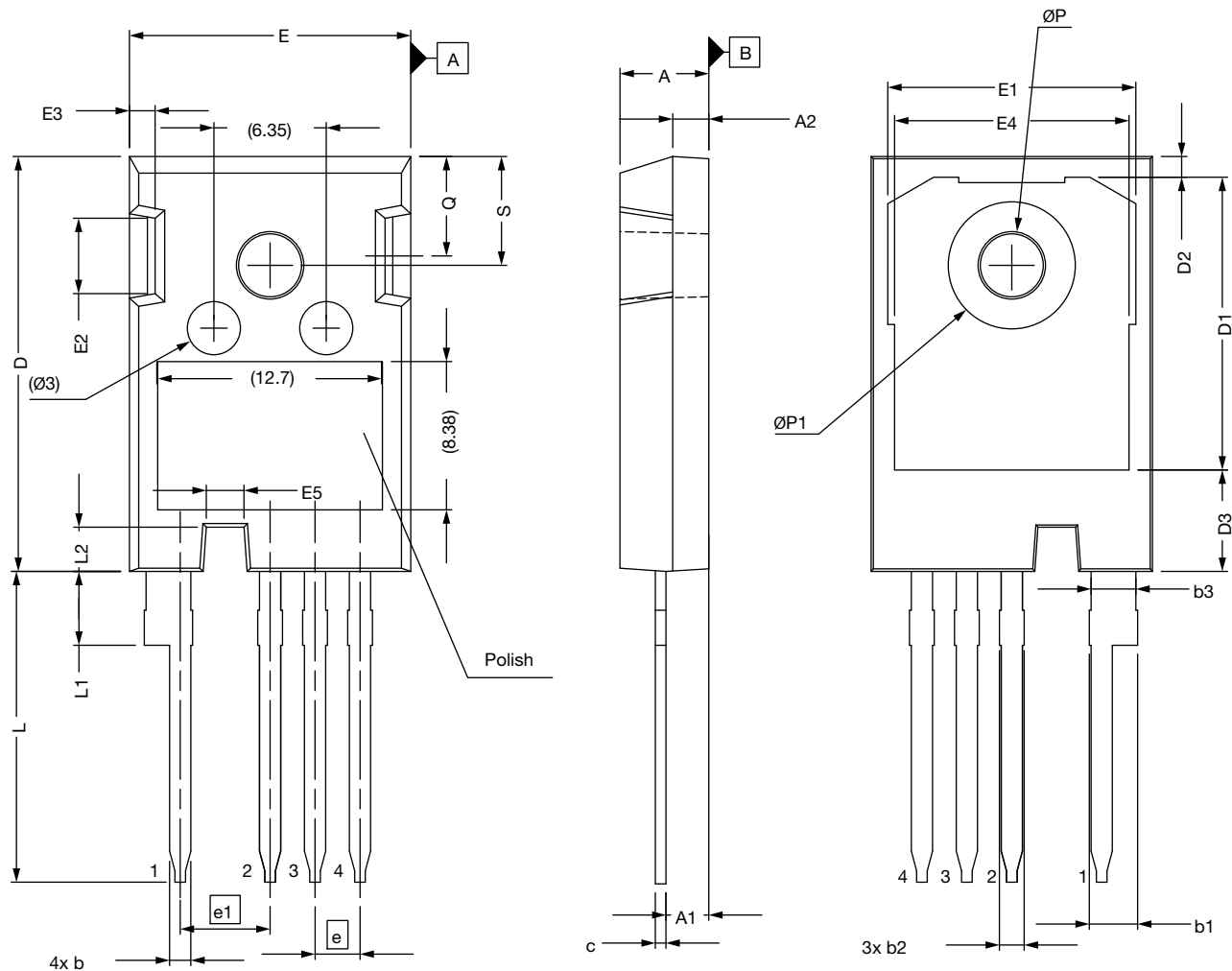
DIM.	MILLIMETERS	
	MIN.	MAX.
A	4.83	5.21
A1	2.29	2.54
A2	1.91	2.16
b	1.07	1.33
b1	2.39	2.94
b3	1.07	1.60
c	0.55	0.68
D	23.30	23.60
D1	16.25	17.65
D2	0.95	1.25
E	15.75	16.13
E1	13.10	14.15
E2	3.68	5.10
E3	1.00	1.90
E4	12.38	13.43
E5	1.95	2.35
e	2.54 BSC.	
e1	5.08 BSC.	
L	17.31	17.82
L1	3.97	4.37
L2	2.35	2.65
ØP	3.51	3.65
Q	5.49	6.00
S	6.04	6.30

Notes

- All dimensions are in mm. Angles are in degrees
- Dimension D and E do not include mold flash
- All metal surfaces: tin plated, except area of cut
- Dimensioning and tolerancing confirm to ASME Y14.5M-1994
- Creepage 1 is 8.58 mm (ref.) which is the distance alongside the surface between drain (pin 1) and trough the notch towards source (pin 2).
Creepage 2 is 7.95 mm (ref.) which is the distance from end of the copper slug on the backside of the package to either pin 2, pin 3 or pin 4



FACILITY CODE: N





DIM.	MILLIMETERS		
	MIN.	NOM.	MAX.
A	4.83	5.02	5.21
A1	2.29	2.41	2.54
A2	1.91	2.00	2.16
b	1.07	1.20	1.33
b1	2.39	2.67	2.94
b2	1.07	1.30	1.60
b3	2.39	2.53	2.69
c	0.55	0.60	0.68
D	23.30	23.45	23.60
D1	16.25	16.55	17.65
D2	0.95	1.19	1.25
D3	5.55	5.71	6.01
E	15.75	15.94	16.13
E1	13.10	14.02	14.15
E2	3.68	4.40	5.10
E3	1.00	1.45	1.90
E4	12.38	13.26	13.43
E5	1.95	2.15	2.35
e	2.54 BSC.		
e1	5.08 BSC.		
L	17.31	17.57	17.82
L1	3.97	4.19	4.37
L2	2.35	2.50	2.65
ØP	3.51	3.61	3.65
ØP1	7.19 ref.		
Q	5.49	5.79	6.00
S	6.04	6.17	6.30
ECN: S25-0851-Rev. C, 18-Jul-2025			
DWG: 6121			

Notes

- All dimensions are in mm
- Dimension D and E do not include mold flash.
- Creepage 1 is 8.40 mm (ref.) which is the distance alongside the surface between drain (pin 1) and trough the notch towards source (pin 2).
Creepage 2 is 7.70 mm (ref.) which is the distance from end of the copper slug on the backside of the package to either pin 2, pin 3 or pin 4



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.